

## **EPC2022**

### **EPC2022** Information

For Reference Only	Part Number Manufacturer Category Description Package	EPC2022 EPC Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single TRANS GAN 100V 3MOHM BUMPED DIE Die	
	Package	For the pricing/inventory/lead time, please contact us	回將殼
		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## **EPC2022** Specifications

Manufacturer Part Number	EPC2022
Manufacturer	EPC
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	Die
Series	eGaN?
FET Type	N-Channel
Technology	GaNFET (Gallium Nitride)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	60A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	5V
Vgs(th) (Max) @ Id	2.5V @ 12mA
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	1500pF @ 50V
Vgs (Max)	+6V, -4V
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	3.2 mOhm @ 25A, 5V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	Die
Package / Case	Die
	Report errors?

#### **EPC2022** Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE BUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about EPC2022, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com